Electronic Supplementary Material (ESI) for ChemComm. This journal is © The Royal Society of Chemistry 2015

Electronic Supplementary Information

Electronic Supplementary Materials for Chemical Communications

SnO₂ nanocrystals anchoring on N-doped graphene for high-performance lithium storage

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Supplementary Materials

Experimental details

Fig. S1 XRD patterns of SnO₂ nanocrystals and SnO₂/N-doped graphene composite.

Fig. S2 TEM (a) and HRTEM (b) images of SnO₂ nanocrystals.

Fig. S3 TGA curve of SnO₂/N-doped graphene composite.

Fig. S4 STEM image (a), Sn (b), C (c) and N (d) elemental mappings of SnO₂/N-

doped graphene composite.

Fig. S5 C1s XPS spectra of GO (a) and SnO₂/N-doped graphene composite (b).

Fig. S6 TEM (a) and HRTEM (b) images of SnO₂/N-doped graphene composite electrode after 1C cycling.

Materials Preparation

Graphite oxide was produced by a modified Hummers method.¹ Graphene oxide suspension (2 mg mL⁻¹) was prepared by dispersing 60 mg graphite oxide into a mixed solution, which contained 20 mL DI water and 10 mL ethylene glycol. Then, 1 g urea and 0.3 g SnCl₄·5H₂O were dissolved into the above solution. The solution was transferred into an autoclave and heated by microwave (MARS6, CEM Corporation, USA) to reach 180 °C and kept for 5 minutes. After naturally cooled, obtained black precipitate was rinsed several times by DI water and absolute ethanol. Last, it was dried under vacuum at 80 °C overnight. For comparison, pristine SnO₂ nanocrystals were obtained by the same process without the addition of graphene oxide.

Materials Characterization

The structure and morphology of the products were characterized by X-ray diffraction (Bruker D8 Focus diffractometer with Cu K α radiation) and transmission electron microscope (FEI Tecnai G2). Thermogravimetric analysis (TGA) was performed on a NETZSCH STA 449F3 simultaneous thermal analyzer in air with a heating rate of 10 °C min⁻¹. X-ray photoelectron spectroscopy (XPS) analysis was carried out using an ESCALABMKLL X-ray photoelectron spectrometer with monochromatic Al K α source.

Electrochemical measurements

A *N*-methyl pyrrolidinone (NMP) slurry consisting of the active material, carbon black and polyvinylidene difluoride (PVDF) with a weight ratio of 8:1:1 was pasted on a copper foil. After drying, the foil was punched into disk electrodes. The electrodes were vacuum dried, weighted and assembled into 2025 coin-type cells, with Li-foil as counter electrode and Celgard 2400 membrane as separator. The electrolyte was 1M LiPF₆ dissolved in a 1:1 (v/v) mixture of ethylene carbonate (EC) and diethyl carbonate (DEC). The cells were galvanostatic cycled between 0.01 and 3V versus Li metal at various C rates using LAND CT2001A battery testing system.



Fig. S1 XRD patterns of SnO $_2$ nanocrystals and SnO $_2$ /N-doped graphene composite.



Fig. S2 TEM (a) and HRTEM (b) images of SnO₂ nanocrystals.



Fig. S3 TGA curve of SnO₂/N-doped graphene composite.



Fig. S4 STEM image (a), Sn (b), C (c) and N (d) elemental mappings of SnO₂/N-doped graphene composite.



Fig. S5 C1s XPS spectra of GO (a) and SnO_2/N -doped graphene composite (b).



Fig. S6 TEM (a) and HRTEM (b) images of SnO₂/N-doped graphene composite electrode after 1C cycling.

References

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